

Theoretical Formalism

(Dated: December 10, 2020)

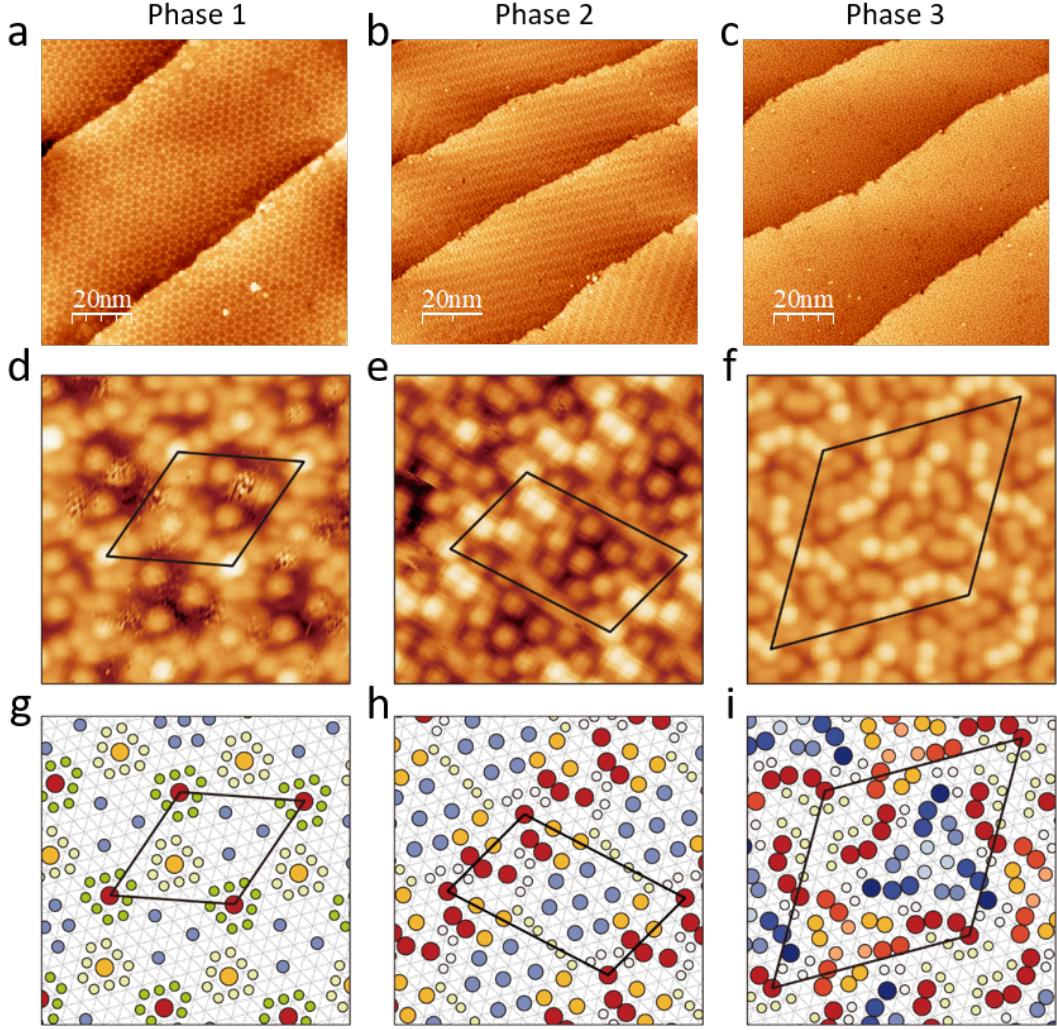


FIG. 1. (Color online) STM characterization of three new superstructures of Sn sub-monolayers on Si(111). (a)-(c) Large-scale STM image (size: $100 \times 100 \text{ nm}^2$) taken on $(3\sqrt{7} \times 3\sqrt{7})R19.1^\circ$, $(\sqrt{133} \times 4\sqrt{3})$ and (13×13) surfaces. They are taken at $U = +3.5V$, $U = -2V$ and $U = -2V$ ($I_t = 100pA$) respectively. (d)-(f) The atomically resolved STM images of them taken at $U = -2V$, $I_t = 200pA$. The surface unit cells of them are marked in black. (g)-(i) The corresponding proposed atomic structural models. The marked surface unit cells in (g)-(i) are the same as these in (d)-(f).

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To have a better understanding of the experimental observations, we adopt the single-band Hubbard model with modulated hopping coefficients and use cluster perturbation theory (CPT)[1, 2] to calculate the spectral function as well as density of states of the model Hamiltonians. For the $(3\sqrt{7} \times 3\sqrt{7})R19.1^\circ$ surface (referred to as Phase 1 in the following), the STM topographic image are shown in Fig. 1(a) and Fig. 1(d). Based on the proposed atomic structural shown in Fig. 1(g), we constructed a single-band Hubbard model with modulated hopping coefficients to describe the system. The model Hamiltonian takes the following form:

$$H = \sum_{\langle i,j \rangle \sigma} t_{ij} (c_{i\sigma}^\dagger c_{j\sigma} + \text{H.c.}) + U \sum_i n_{i\uparrow} n_{i\downarrow} \quad (1)$$

[1] C. Gros and R. Valentí, *Phys. Rev. B* **48**, 418 (1993).

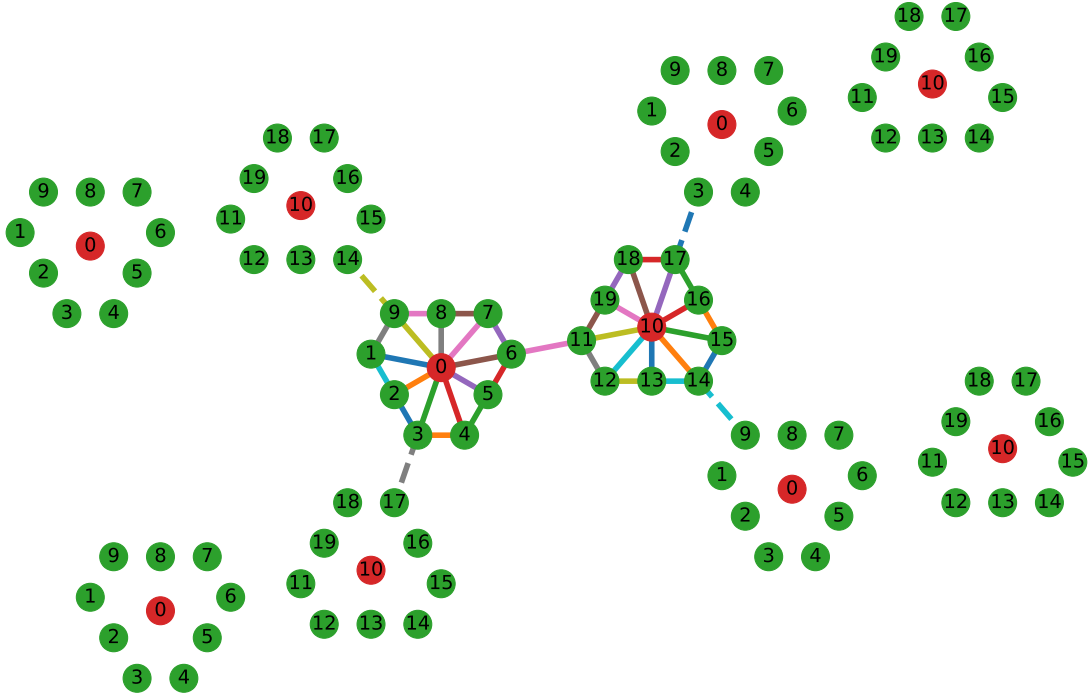


FIG. 2. (Color online) Demonstration of the hopping terms for Phase 1. The unit cell has twenty sites labeled from 0 to 19. The solid and dashed lines correspond to the hopping terms $t_{ij}(c_{i\sigma}^\dagger c_{j\sigma} + \text{H.c.})$, where $t_{ij} = -1/r_{ij}^2$ and r_{ij} is the distance from i -th to j -th site.

[2] D. Sénéchal, D. Perez, and M. Pioro-Ladrière, *Phys. Rev. Lett.* **84**, 522 (2000).